## NSN 5961-00-011-5712

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-011-5712 **Inclosure Material:** Glass and metal **Overall Length:** 0.550 inches **Overall Diameter:** 0.487 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-10 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.486 inches and 0.500 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 reverse voltage, peak **Current Rating Per Characteristic:** 6.00 milliamperes average forward current averaged over a full 60-hz cycle **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius case **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug **Specification Data:** 80131-release2544 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

A110a0